

## LDO Regulator -Ultra-Low I<sub>Q,</sub> CMOS <sup>150 mA</sup> NCV8170

The NCV8170 series of CMOS low dropout regulators are designed specifically for continuous on battery-powered applications which require ultra-low quiescent current. The ultra-low consumption of typ. 500~nA ensures long battery life and dynamic transient boost feature improves device transient response for wireless communication applications. The device is available in small  $1\times1~\text{mm}$  xDFN4 and SOT-563~packages.

#### **Features**

• Operating Input Voltage Range: 2.2 V to 5.5 V

• Output Voltage Range: 1.2 V to 3.6 V (0.1 V Steps)

• Ultra-Low Quiescent Current Typ. 0.5 μA

• Low Dropout: 170 mV Typ. at 150 mA

• High Output Voltage Accuracy ±1%

• Stable with Ceramic Capacitors 1 μF

• Over-Current Protection

• Thermal Shutdown Protection

NCV8170A for Active Discharge Option

• Available in Small 1 × 1 mm xDFN4 and SOT-563 Packages

- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **Typical Applications**

- Telematics and Infotainment Systems
- Automotive Keyless Entry Systems
- ADAS Camera Modules
- Navigation Systems

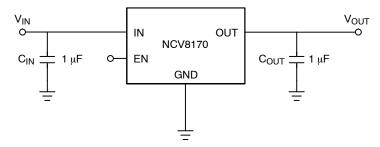


Figure 1. Typical Application Schematic



XDFN4 MX SUFFIX CASE 711AJ



SOT-563 XV SUFFIX CASE 463A

## **MARKING DIAGRAMS**

#### XDFN4



XX = Specific Device Code M = Date Code

## SOT-563



XX = Specific Device CodeM = Month Code= Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 19 of this data sheet.

## **PIN FUNCTION DESCRIPTION**

| Pin No.<br>XDFN4 | Pin No.<br>SOT-563 | Pin Name | Description                  |
|------------------|--------------------|----------|------------------------------|
| 4                | 1                  | IN       | Power Supply Input Voltage   |
| 2                | 2                  | GND      | Power Supply Ground          |
| 3                | 6                  | EN       | Chip Enable Pin (Active "H") |
| 1                | 3                  | OUT      | Output Pin                   |
| EPAD             |                    | EPAD     | Internally Connected to GND  |
|                  | 4                  | NC       | No Connect                   |
|                  | 5                  | GND      | Power Supply Ground          |

## **ABSOLUTE MAXIMUM RATINGS**

| Symbol              | Rating                                    | Value                         | Unit |
|---------------------|---|-------------------------------|------|
| V <sub>IN</sub>     | Input Voltage (Note 1)                    | 6.0                           | V    |
| V <sub>OUT</sub>    | Output Voltage                            | -0.3 to V <sub>IN</sub> + 0.3 | V    |
| V <sub>CE</sub>     | Chip Enable Input                         | -0.3 to 6.0                   | V    |
| T <sub>J(MAX)</sub> | Maximum Junction Temperature              | 125                           | °C   |
| T <sub>STG</sub>    | Storage Temperature                       | -55 to 150                    | °C   |
| ESD <sub>HBM</sub>  | ESD Capability, Human Body Model (Note 2) | 2000                          | V    |
| ESD <sub>MM</sub>   | ESD Capability, Machine Model (Note 2)    | 200                           | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

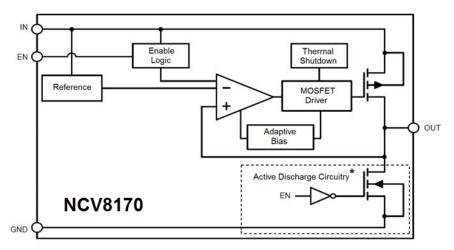
- 2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114) ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latchup Current Maximum Rating tested per JEDEC standard: JESD78

## THERMAL CHARACTERISTICS

| Symbol         | Rating   | Value      | Unit |
|----------------|--|------------|------|
| $R_{	heta JA}$ | Thermal Characteristics, Thermal Resistance, Junction-to-Air | 252        | °C/W |
|                | XDFN4 1 × 1 mm<br>SOT-563                                    | 250<br>200 |      |



\* Active discharge feature is present only in NCV8170AxxvvvTyG devices

Figure 2. Simplified Block Diagram

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.2 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 2.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. \ Typical values are at \ T_{A} = +25^{\circ}C.) \ (Note 3)$ 

| Symbol              | Parameter   | Test Conditions   | Min    | Тур      | Max    | Unit  |
|---------------------|---|---|--------|----------|--------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2    | -        | 5.5    | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 1.188  | 1.2      | 1.212  | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$   | 1.176  | 1.2      | 1.224  |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 2.5 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA  | _      | 0.05     | 0.20   | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 2.5 \text{ V}$   | -20    | 1        | 20     | mV    |
| $V_{DO}$            | Dropout Voltage                                       | (Note 4)  | _      | -        | -      | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 5)  | 150    | -        | -      | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | _      | 225      | -      | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | _      | 0.5      | 0.9    | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C  | _      | 0.1      | 0.5    | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2    | -        | -      | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _      | -        | 0.4    | V     |
| I <sub>EN</sub>     | EN Pin Current  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 6)  | -      | 10       | -      | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $ f = 1 \text{ kHz, V}_{\text{IN}} = 2.2 \text{ V} + 200 \text{ mVpp Modulation} $ $ I_{\text{OUT}} = 150 \text{ mA} $ $ I_{\text{OUT}} = 10 \text{ mA} $ | _<br>_ | 57<br>63 | _<br>_ | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA, f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$  | -      | 85       | -      | μVrms |
| $R_{LOW}$           | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 6)   | -      | 100      | _      | Ω     |
| $T_{SD}$            | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 6)   | -      | 175      | _      | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 6)   | _      | 25       | _      | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 Not Characterized at V<sub>IN</sub> = 2.2 V, V<sub>OUT</sub> = 1.2 V, I<sub>OUT</sub> = 150 mA.

<sup>5.</sup> Respect SOA.

<sup>6.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.5 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 2.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. \ Typical values are at \ T_{A} = +25^{\circ}C.) \ (Note \ 7)$ 

| Symbol              | Parameter   | Test Conditions  | Min   | Тур  | Max   | Unit  |
|---------------------|---|--|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |  | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C   | 1.485 | 1.5  | 1.515 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$          | 1.470 | 1.5  | 1.530 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.3 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                       | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4.3 \text{ V}$                          | -20   | -    | 20    | mV    |
| V <sub>DO</sub>     | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 8)   | -     | -    | -     | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 9)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V   | -     | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA  | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                   | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"   | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"   | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pin Current  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 10)                            | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 2.5 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA         | -     | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA, f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 90   | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 10)                       | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 10)                   | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 10)                             | -     | 25   | _     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

Not Characterized at V<sub>IN</sub> = 2.2 V, V<sub>OUT</sub> = 1.5 V, I<sub>OUT</sub> = 150 mA.

<sup>10.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.8 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 2.8 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 11)$ 

| Symbol              | Parameter   | Test Conditions   | Min      | Тур  | Max   | Unit  |
|---------------------|---|---|----------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2      | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 1.782    | 1.8  | 1.818 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$         | 1.764    | 1.8  | 1.836 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 2.8 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | _        | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 2.8 \text{ V}$                         | -20      | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 12)   | <b>-</b> | 350  | 500   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 13)   | 150      | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | _        | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | _        | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | _        | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2      | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _        | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | $V_{EN} \le V_{IN} \le 5.5 \text{ V (Note 14)}$                               | _        | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 2.8 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -        | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -        | 95   | -     | μVrms |
| $R_{LOW}$           | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 14)                      | -        | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 14)                  | -        | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 14)                            | _        | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

11. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

 $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 12. Characterized when  $V_{OUT}$  falls 54 mV below the regulated voltage and only for devices with  $V_{OUT} = 1.8$  V.

<sup>14.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 2.5 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 3.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 15)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.475 | 2.5  | 2.525 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$         | 2.450 | 2.5  | 2.550 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 3.5 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 3.5 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 16)   | _     | 240  | 350   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 17)   | 150   | -    | _     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 18)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 3.5 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 18)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 18)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 18)                            | -     | 25   | _     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

 $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 16. Characterized when  $V_{OUT}$  falls 75 mV below the regulated voltage and only for devices with  $V_{OUT} = 2.5$  V.

<sup>18.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 2.8 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 3.8 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 19)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.772 | 2.8  | 2.828 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$         | 2.744 | 2.8  | 2.856 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 3.8 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | _     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 3.8 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 20)   | _     | 210  | 315   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 21)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 195  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 22)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 3.8 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 40   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 22)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 22)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 22)                            | _     | 25   | _     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions.

19. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 20. Characterized when  $V_{OUT}$  falls 84 mV below the regulated voltage and only for devices with  $V_{OUT} = 2.8$  V.

<sup>22.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.0 V**

 $(-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}; \text{V}_{\text{IN}} = 4.0 \text{ V}; \text{I}_{\text{OUT}} = 1 \text{ mA, } \text{C}_{\text{IN}} = \text{C}_{\text{OUT}} = 1.0 \text{ } \mu\text{F}, \text{ unless otherwise noted.}$  Typical values are at T<sub>A</sub> = +25°C.) (Note 23)

| Symbol              | Parameter   | Test Conditions   | Min  | Тур  | Max  | Unit  |
|---------------------|---|---|------|------|------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2  | -    | 5.5  | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.97 | 3.0  | 3.03 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$         | 2.94 | 3.0  | 3.06 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.0 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -    | 0.05 | 0.20 | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4 \text{ V}$                           | -20  | 1    | 20   | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 24)   | -    | 190  | 260  | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 25)   | 150  | -    | -    | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -    | 195  | -    | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -    | 0.5  | 0.9  | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -    | 0.1  | 0.5  | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2  | -    | -    | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -    | -    | 0.4  | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 26)                           | -    | 10   | -    | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 4.0 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | =    | 47   | -    | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -    | 120  | -    | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 26)                      | -    | 100  | -    | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 26)                  | -    | 175  | -    | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 26)                            | -    | 25   | -    | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

23. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

 $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 24. Characterized when  $V_{OUT}$  falls 90 mV below the regulated voltage and only for devices with  $V_{OUT} = 3.0$  V.

<sup>26.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.3 V**

 $(-40^{\circ}C \leq T_{J} \leq 125^{\circ}C; \ V_{IN} = 4.3 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 27) \ (Note \ 27)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 3.267 | 3.3  | 3.333 | V     |
|                     |   | -40°C ≤ T <sub>J</sub> ≤ 125°C  | 3.234 | 3.3  | 3.366 | 1     |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.3 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | _     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4.3 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 28)   | -     | 180  | 250   | mV    |
| l <sub>out</sub>    | Output Current  | (Note 29)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 195  | -     | mA    |
| ΙQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 30)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 4.3 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | =     | 41   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 30)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 30)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 30)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

27.Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

<sup>27.</sup>Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
28.Characterized when V<sub>OUT</sub> falls 99 mV below the regulated voltage and only for devices with V<sub>OUT</sub> = 3.3 V.

<sup>29.</sup> Respect SOA.

<sup>30.</sup> Guaranteed by design and characterization.

## **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.6 V**

 $(-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}; \text{V}_{\text{IN}} = 4.6 \text{ V}; \text{I}_{\text{OUT}} = 1 \text{ mA}, \text{C}_{\text{IN}} = \text{C}_{\text{OUT}} = 1.0 \,\mu\text{F}, \text{ unless otherwise noted.}$  Typical values are at T<sub>A</sub> = +25°C.) (Note 31)

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 3.564 | 3.6  | 3.636 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$         | 3.528 | 3.6  | 3.672 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.6 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | _     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4.6 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 32)   | _     | 170  | 240   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 33)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 195  | _     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | _     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | _     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 34)                           | _     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 4.6 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 30   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 130  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 34)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 34)                  | _     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 34)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

32. Characterized when V<sub>OUT</sub> falls 108 mV below the regulated voltage and only for devices with V<sub>OUT</sub> = 3.6 V.

34. Guaranteed by design and characterization.

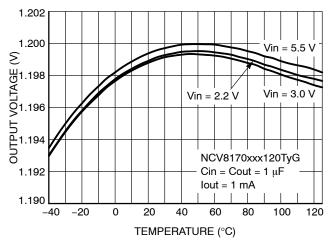


Figure 3. Output Voltage vs. Temperature, Vout = 1.2 V

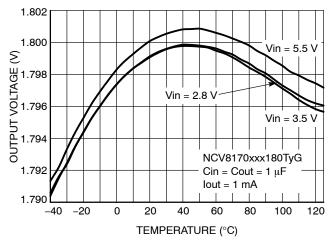


Figure 4. Output Voltage vs. Temperature, Vout = 1.8 V

<sup>31.</sup> Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

<sup>33.</sup> Respect SOA.

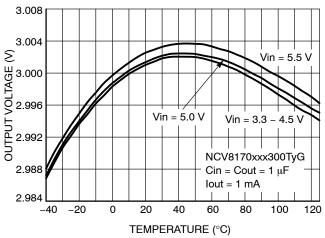


Figure 5. Output Voltage vs. Temperature, Vout = 3.0 V

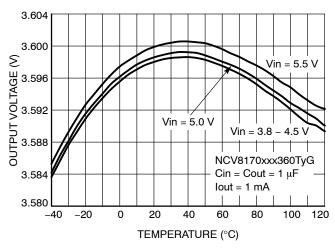


Figure 6. Output Voltage vs. Temperature, Vout = 3.6 V

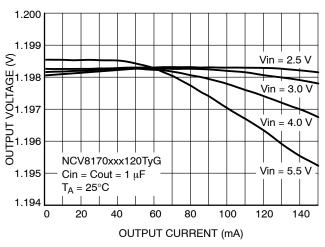


Figure 7. Output Voltage vs. Output Current, Vout = 1.2 V

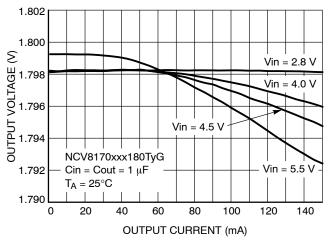


Figure 8. Output Voltage vs. Output Current, Vout = 1.8 V

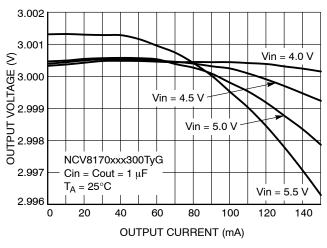


Figure 9. Output Voltage vs. Output Current, Vout = 3.0 V

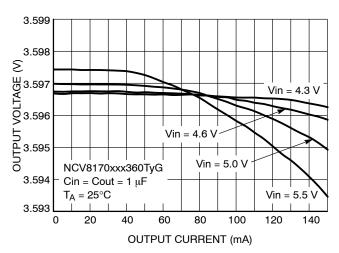


Figure 10. Output Voltage vs. Output Current, Vout = 3.6 V

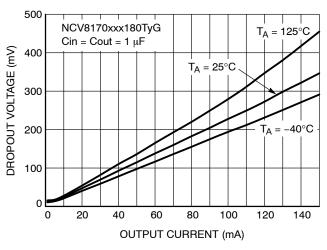


Figure 11. Dropout Voltage vs. Output Current, Vout = 1.8 V

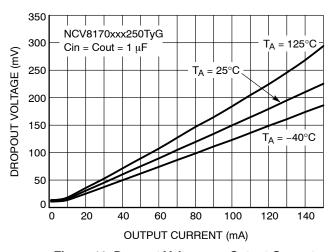


Figure 12. Dropout Voltage vs. Output Current, Vout = 2.5 V

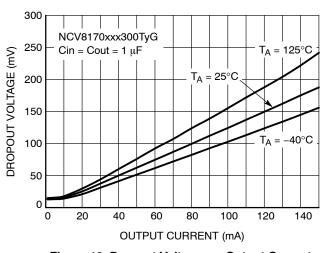


Figure 13. Dropout Voltage vs. Output Current, Vout = 3.0 V

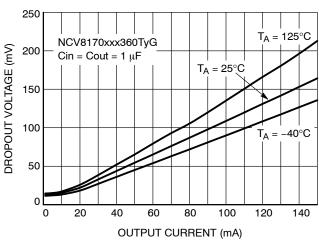


Figure 14. Dropout Voltage vs. Output Current, Vout = 3.6 V

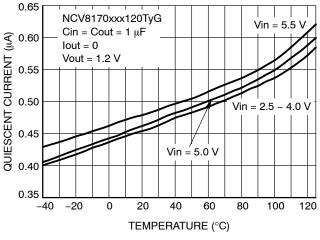


Figure 15. Quiescent Current vs. Temperature, Vout = 1.2 V

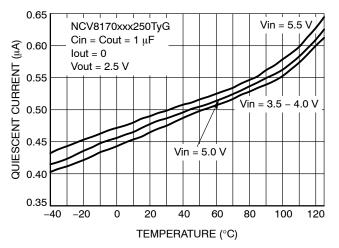


Figure 16. Quiescent Current vs. Temperature, Vout = 2.5 V

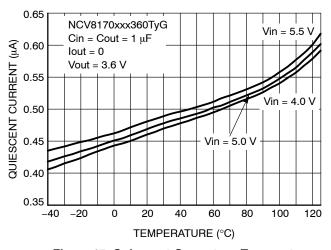


Figure 17. Quiescent Current vs. Temperature, Vout = 3.6 V

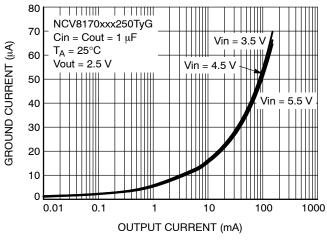


Figure 19. Ground Current vs. Output Current, Vout = 2.5 V

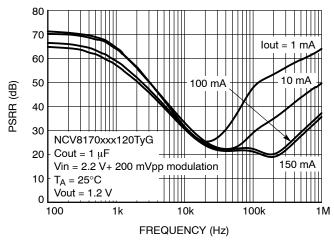


Figure 21. PSRR vs. Frequency, Vout = 1.2 V

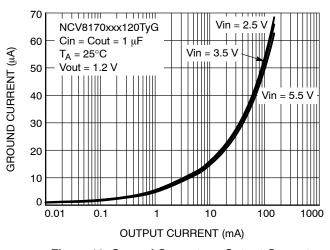


Figure 18. Ground Current vs. Output Current, Vout = 1.2 V

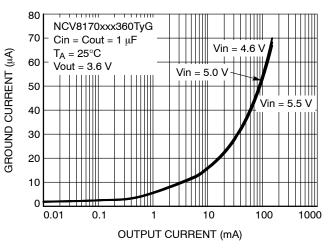


Figure 20. Ground Current vs. Output Current, Vout = 3.6 V

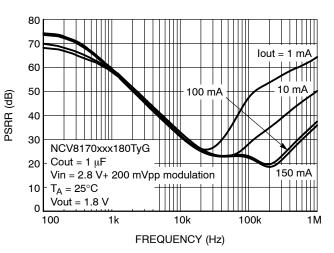


Figure 22. PSRR vs. Frequency, Vout = 1.8 V

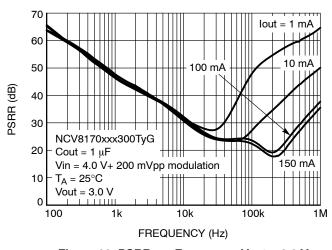


Figure 23. PSRR vs. Frequency, Vout = 3.0 V

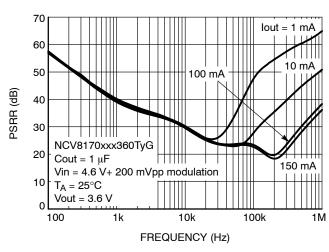


Figure 24. PSRR vs. Frequency, Vout = 3.6 V

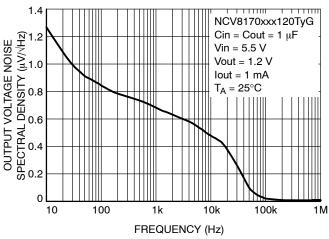


Figure 25. Output Voltage Noise Spectral Density, Vout = 1.2 V

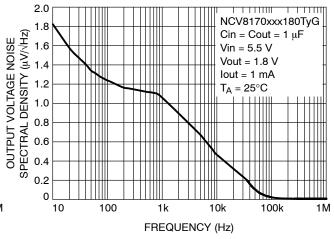


Figure 26. Output Voltage Noise Spectral Density, Vout = 1.8 V

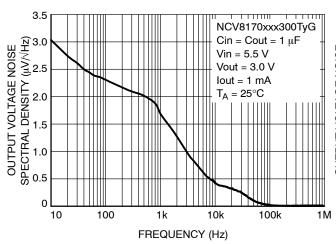


Figure 27. Output Voltage Noise Spectral Density, Vout = 3.0 V

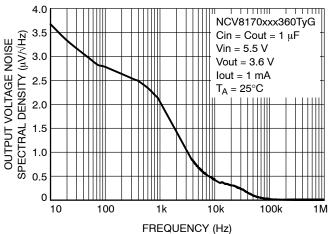


Figure 28. Output Voltage Noise Spectral Density, Vout = 3.6 V

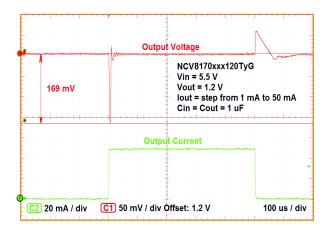


Figure 29. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 1.2 V

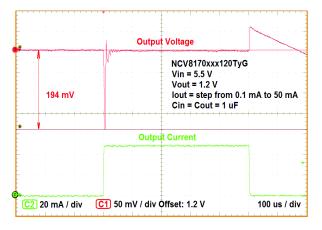


Figure 30. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 1.2 V

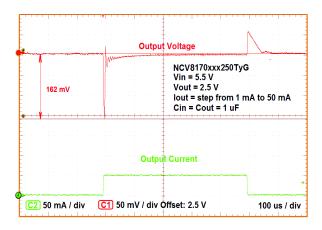


Figure 31. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 2.5 V

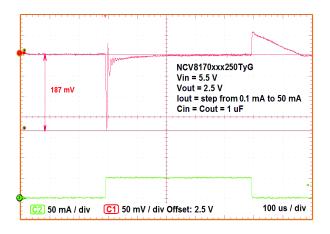


Figure 32. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 2.5 V

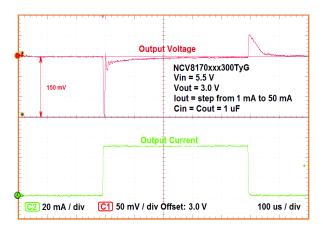


Figure 33. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 3.0 V

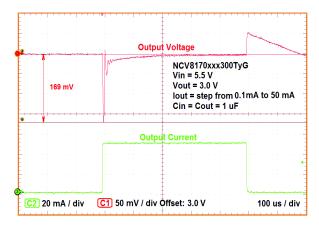


Figure 34. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 3.0 V

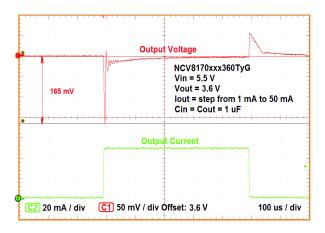


Figure 35. Load Transient Response at Load Step from 1mA to 50 mA, Vout= 3.6 V

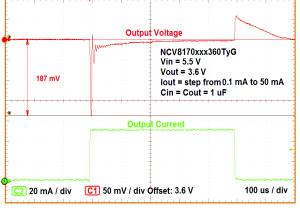


Figure 36. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 3.6 V

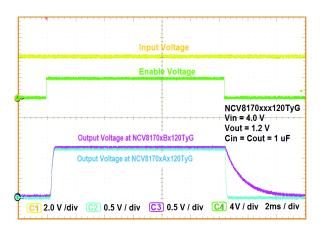


Figure 37. Output Voltage With and Without Active Discharge Feature, Vout = 1.2 V

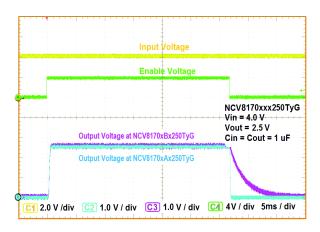


Figure 38. Output Voltage With and Without Active Discharge Feature, Vout = 2.5 V

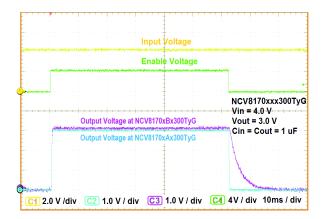


Figure 39. Output Voltage With and Without Active Discharge Feature, Vout = 3.0 V

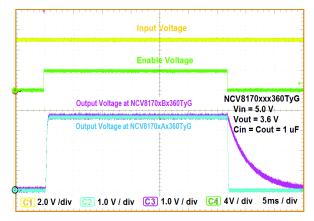


Figure 40. Output Voltage With and Without Active Discharge Feature, Vout = 3.6 V

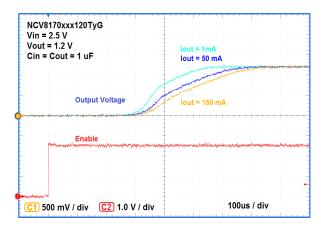


Figure 41. Enable Turn-on Response at Vout = 1.2 V

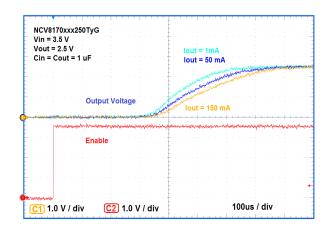


Figure 42. Enable Turn-on Response at Vout = 2.5 V

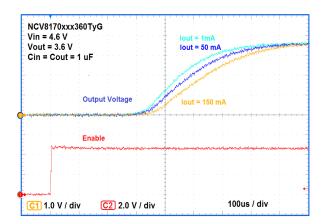


Figure 43. Enable Turn-on Response at Vout = 3.6 V

## **APPLICATIONS INFORMATION**

#### General

The NCV8170 is a high performance 150 mA Linear Regulator with Ultra Low IQ. This device delivers low Noise and high Power Supply Rejection Ratio with excellent dynamic performance due to employing the Dynamic Quiescent Current adjustment which assure ultra low IQ consumption at no – load state. These parameters make this device very suitable for various battery powered applications.

## Input Decoupling (CIN)

It is recommended to connect at least a 1  $\mu$ F Ceramic X5R or X7R capacitor between IN and GND pins of the device. This capacitor will provide a low impedance path for any unwanted AC signals or Noise superimposed onto constant Input Voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes.

Higher capacitance and lower ESR Capacitors will improve the overall line transient response.

## Output Decoupling (COUT)

The NCV8170 does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The device is designed to be stable with standard ceramics capacitors with values of 1.0  $\mu F$  or greater up to 10  $\mu F$ . The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended. There is recommended connect the output capacitor as close as possible to the output pin of the regulator.

#### **Enable Operation**

The NCV8170 uses the EN pin to enable /disable its device and to activate /deactivate the active discharge function at devices with this feature. If the EN pin voltage is pulled below 0.4 V the device is guaranteed to be disable. The active discharge transistor at the devices with Active Discharge Feature is activated and the output voltage VOUT is pulled to GND through an internal circuitry with effective resistance about 100 ohms.

If the EN pin voltage is higher than 1.2 V the device is guaranteed to be enabled. The internal active discharge

circuitry is switched off and the desired output voltage is available at output pin. In case the Enable function is not required the EN pin should be connected directly to input pin.

#### Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown point (TSD = 175°C typical) the device goes to disabled state and the output voltage is not delivered until the die temperature decreases to 150°C. The Thermal Shutdown feature provides a protection from a catastrophic device failure at accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.

#### **Power Dissipation and Heat sinking**

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. The maximum power dissipation the NCV8170 device can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_{A}\right]}{R_{A,IA}}$$
 (eq. 1)

The power dissipated by the NCV8170 device for given application conditions can be calculated from the following equations:

$$P_{D} \approx V_{IN} (I_{GND}(I_{OUT})) + I_{OUT} (V_{IN} - V_{OUT}) \qquad (eq. 2)$$

or

$$V_{IN(MAX)} \approx \frac{P_{D(MAX)} + (V_{OUT} \times I_{OUT})}{I_{OUT} + I_{GND}}$$
 (eq. 3)

## Hints

VIN and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCV8170, and make traces as short as possible.

## **ORDERING INFORMATION**

| Device                     | Nominal Output<br>Voltage | Marking | Active Discharge | Package         | Shipping <sup>†</sup>    |
|----------------------------|---------------------------|---------|------------------|-----------------|--------------------------|
| NCV8170AMX120TCG (Note 35) | 1.2                       | CC      |                  |                 |                          |
| NCV8170AMX150TCG (Note 35) | 1.5                       | CJ      |                  |                 |                          |
| NCV8170AMX180TCG (Note 35) | 1.8                       | CD      |                  |                 |                          |
| NCV8170AMX250TCG (Note 35) | 2.5                       | CE      |                  |                 |                          |
| NCV8170AMX280TCG (Note 35) | 2.8                       | CF      | Yes              |                 |                          |
| NCV8170AMX300TCG (Note 35) | 3.0                       | CA      |                  | XDFN4 1 0 × 1 0 |                          |
| NCV8170AMX310TCG           | 3.1                       | CN      |                  |                 |                          |
| NCV8170AMX330TCG (Note 35) | 3.3                       | CG      |                  |                 |                          |
| NCV8170AMX360TCG (Note 35) | 3.6                       | CM      |                  | XDFN4 1.0 x 1.0 | 3000 or 5000 /           |
| NCV8170BMX120TCG (Note 35) | 1.2                       | 3C      |                  | (Pb-Free)       | Tape & Reel<br>(Note 35) |
| NCV8170BMX150TCG (Note 35) | 1.5                       | 3J      |                  |                 |                          |
| NCV8170BMX180TCG (Note 35) | 1.8                       | 3D      |                  |                 |                          |
| NCV8170BMX250TCG (Note 35) | 2.5                       | 3E      |                  |                 |                          |
| NCV8170BMX280TCG (Note 35) | 2.8                       | 3F      | No               |                 |                          |
| NCV8170BMX300TCG           | 3.0                       | ЗА      |                  |                 |                          |
| NCV8170BMX310TCG (Note 35) | 3.1                       | 3Y      |                  |                 |                          |
| NCV8170BMX330TCG (Note 35) | 3.3                       | 3G      |                  |                 |                          |
| NCV8170BMX360TCG (Note 35) | 3.6                       | 3M      |                  |                 |                          |
| NCV8170AXV120T2G           | 1.2                       | CC      |                  |                 |                          |
| NCV8170AXV150T2G           | 1.5                       | CJ      |                  |                 |                          |
| NCV8170AXV180T2G           | 1.8                       | CD      |                  |                 |                          |
| NCV8170AXV250T2G           | 2.5                       | CE      |                  |                 |                          |
| NCV8170AXV280T2G           | 2.8                       | CF      | Yes              |                 |                          |
| NCV8170AXV300T2G           | 3.0                       | CA      |                  |                 |                          |
| NCV8170AXV310T2G           | 3.1                       | CN      |                  |                 |                          |
| NCV8170AXV330T2G           | 3.3                       | CG      |                  |                 |                          |
| NCV8170AXV360T2G           | 3.6                       | CM      |                  | SOT - 563       | 4000 / Tape &            |
| NCV8170BXV120T2G           | 1.2                       | 3C      |                  | (Pb-Free)       | Reel                     |
| NCV8170BXV150T2G           | 1.5                       | 3J      |                  |                 |                          |
| NCV8170BXV180T2G           | 1.8                       | 3D      | ]                |                 |                          |
| NCV8170BXV250T2G           | 2.5                       | 3E      | ]                |                 |                          |
| NCV8170BXV280T2G           | 2.8                       | 3F      | No               |                 |                          |
| NCV8170BXV300T2G           | 3.0                       | ЗА      | ]                |                 |                          |
| NCV8170BXV310T2G           | 3.1                       | 3Y      | ]                |                 |                          |
| NCV8170BXV330T2G           | 3.3                       | 3G      | ]                |                 |                          |
| NCV8170BXV360T2G           | 3.6                       | 3N      |                  |                 |                          |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
35. Products processed after October 1, 2022 are shipped with quantity 5000 units / tape & reel.

## MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



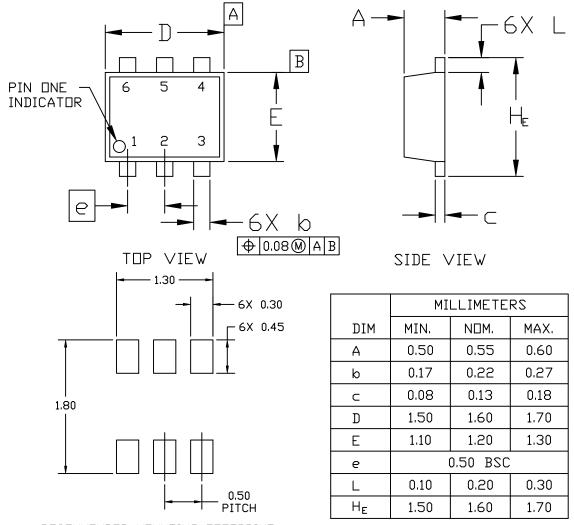


SOT-563, 6 LEAD CASE 463A ISSUE H

**DATE 26 JAN 2021** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



## RECOMMENDED MOUNTING FOOTPRINT\*

For additional information on our Pb-Free strategy and soldering details, please download the IIN Semiconductor Soldering and Mounting Techniques Reference Manual, SILDERRM/D.

| DOCUMENT NUMBER: | 98AON11126D     | Electronic versions are uncontrolled except when accessed directly from the Document Repository<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |
|------------------|-----------------|--|-------------|
| DESCRIPTION:     | SOT-563, 6 LEAD |  | PAGE 1 OF 2 |

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

## **SOT-563, 6 LEAD**

CASE 463A ISSUE H

2

1

**DATE 26 JAN 2021** 

| STYLE 1:<br>PIN 1. EMITTER 1<br>2. BASE 1<br>3. COLLECTOR 2<br>4. EMITTER 2<br>5. BASE 2<br>6. COLLECTOR 1 | STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1                    | STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE   |
|--|---|--|
| STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR                        | STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE 4. ANODE 5. CATHODE 6. CATHODE                                  | STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE                     |
| STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE                                 | STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN  | STYLE 9:<br>PIN 1. SDURCE 1<br>2. GATE 1<br>3. DRAIN 2<br>4. SDURCE 2<br>5. GATE 2<br>6. DRAIN 1 |
| STYLE 10:<br>PIN 1. CATHODE 1<br>2. N/C<br>3. CATHODE 2<br>4. ANODE 2<br>5. N/C<br>6. ANODE 1              | STYLE 11:<br>PIN 1. EMITTER 2<br>2. BASE 2<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. BASE 1<br>6. COLLECTOR 2 |  |

## GENERIC MARKING DIAGRAM\*



XX = Specific Device CodeM = Month Code= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DOCUMENT NUMBER: | 98AON11126D     | Electronic versions are uncontrolled except when accessed directly from the Document Repositor,<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |
|------------------|-----------------|--|-------------|
| DESCRIPTION:     | SOT-563, 6 LEAD |  | PAGE 2 OF 2 |

ON Semiconductor and III are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





PIN ONE

REFERENCE

2X 0.05 C

2X 0.05 C

// 0.05 C

□ 0.05 C

NOTE 4

## XDFN4 1.0x1.0, 0.65P CASE 711AJ ISSUE C

В

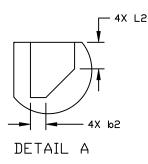
(A3)

SEATING

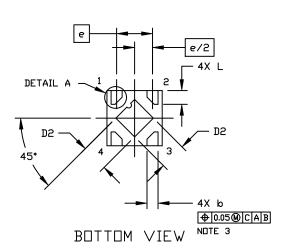
**DATE 08 MAR 2022** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER. ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSION & APPLIES TO THE PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.20 FROM THE TERMINAL TIPS.
- 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

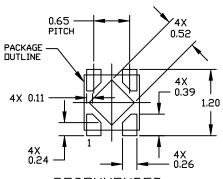


|     | MILLIMETERS |      |      |
|-----|-------------|------|------|
| DIM | MIN         | NDM  | MAX  |
| Α   | 0.33        | 0.38 | 0.43 |
| A1  | 0.00        | -    | 0.05 |
| A3  | 0.10 REF    |      |      |
| b   | 0.15        | 0.20 | 0.25 |
| b2  | 0.02        | 0.07 | 0.12 |
| D   | 0.90        | 1.00 | 1.10 |
| D2  | 0.43        | 0.48 | 0.53 |
| Ε   | 0.90        | 1.00 | 1.10 |
| е   | 0.65 BSC    |      |      |
| L   | 0.20        |      | 0.30 |
| L2  | 0.07        |      | 0.17 |



TOP VIEW

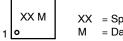
SIDE VIEW



# RECOMMENDED MOUNTING FOOTPRINT

\* FOR ADDITIONAL INFORMATION ON OUR PO-FRE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNT TECHNIQUES REFERENCE MANUAL, SOLDERRM/D

## GENERIC MARKING DIAGRAM\*



XX = Specific Device Code
M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DOCUMENT NUMBER: | 98AON67179E           | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |
|------------------|-----------------------|---|-------------|
| DESCRIPTION:     | XDFN4, 1.0X1.0, 0.65P |   | PAGE 1 OF 1 |

onsemi and ONSemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales